

Title (en)

METHOD FOR APPLYING AN OVERGROWTH LAYER ONTO A SEED LAYER

Title (de)

VERFAHREN ZUR AUFBRINGUNG EINER ÜBERWUCHSSCHICHT AUF EINE KEIMSCHICHT

Title (fr)

PROCÉDÉ POUR APPLIQUER UNE COUCHE DE SURCROISSANCE SUR UNE COUCHE GERME

Publication

EP 3298181 A1 20180328 (DE)

Application

EP 15724285 A 20150521

Priority

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Abstract (en)

[origin: WO2016184523A1] The invention relates to a method for applying a masked overgrowth layer (14) onto a seed layer (2) for the production of semiconductor components, characterized in that a mask (6) for masking the overgrowth layer (14) is embossed on the seed layer (2).

IPC 8 full level

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Citation (search report)

See references of WO 2016184523A1

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